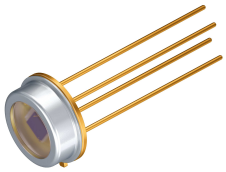
Silicon Dual Photodiode
Version 1.4

SFH 221



Features:

- Especially suitable for applications from 400 nm to 1100 nm
- High photosensitivity
- Hermetically sealed metal package (similar to TO-5), suitable up to 125 °C
- Double diode with extremely high homogeneousness

Applications

- Industrial electronics
- For control and drive circuits
- Edge drives
- Follow-up control

Ordering Information

Type:	Ordering Code
SFH 221	Q62702P0270

Note:: *For operating conditions of T_A > 85 °C please contact us.*

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Maximum Ratings (T_A = 25 °C)

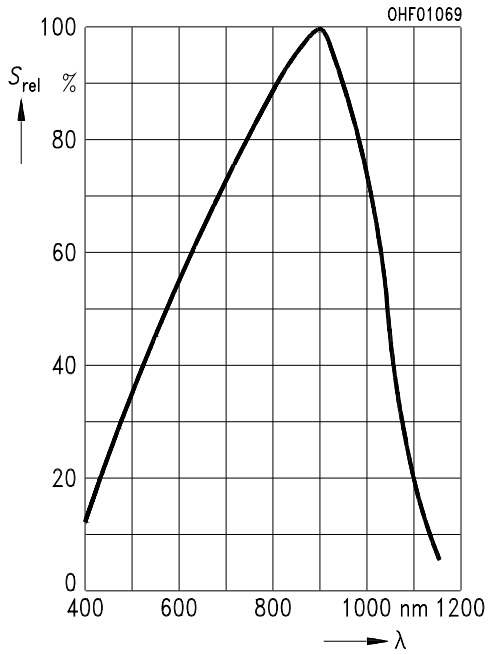
Parameter	Symbol	Values	Unit
Operating and storage temperature range	T_{op}; T_{stg}	-40 ... 125	°C
Reverse voltage	V_R	10	V
Insulation voltage vs. package	V_{IS}	100	V
Total Power dissipation	P_{tot}	50	mW
ESD withstand voltage (acc. to ANSI/ ESDA/ JEDEC JS-001 - HBM)	V_{ESD}	2000	V

Characteristics (T_A = 25 °C, per single diode)

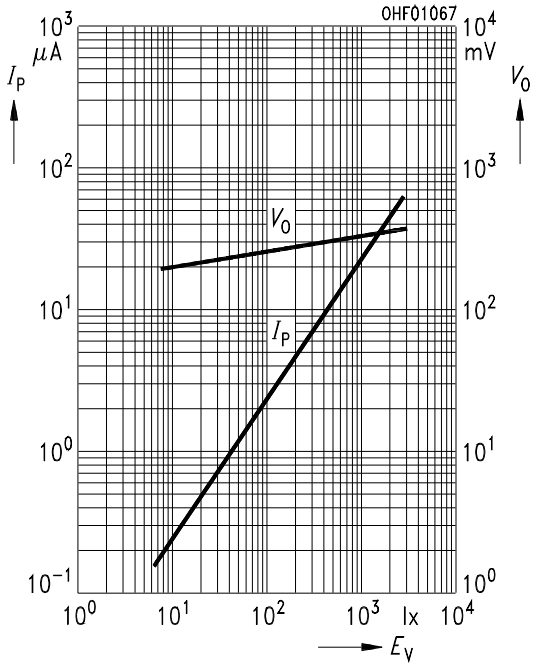
Parameter		Symbol	Values	Unit
Spectral sensitivity (V_R = 5 V, standard light A, T = 2856 K)	(typ)	S	24 (≥ 15)	nA/lx
Wavelength of max. sensitivity	(typ)	$\lambda_{S\ max}$	900	nm
Spectral range of sensitivity	(typ)	$\lambda_{10\%}$	(typ) 400 ... 1100	nm
Radiant sensitive area	(typ)	A	1.54	mm^2
Dimensions of radiant sensitive area	(typ)	L x W	0.7 x 2.2	mm x mm
Half angle	(typ)	φ	± 55	°
Dark current (V_R = 10 V)	(typ (max))	I_R	10 (≤ 100)	nA
Spectral sensitivity of the chip (λ = 850 nm)	(typ)	$S_{\lambda\ typ}$	0.55	A / W
Max. deviation from average for each single diode	(typ)	ΔS	±5	%
Quantum yield of the chip (λ = 850 nm)	(typ)	η	0.80	Electrons /Photon
Open-circuit voltage (E_v = 1000 lx, Std. Light A)	(typ (min))	V_O	330 (≥ 280)	mV
Short-circuit current (E_v = 1000 lx, Std. Light A)	(typ)	I_{SC}	24	µA
Insulation current (V_{IS} = 100 V)	(typ (max))	I_{IS}	0.1 (≤ 1)	nA
Rise and fall time (V_R = 5 V, R_L = 1 kΩ, λ = 850 nm)	(typ)	t_r, t_f	0.5	µs
Forward voltage (I_F = 40 mA, E = 0)	(typ)	V_F	1	V

Parameter		Symbol	Values	Unit
Capacitance (V_R = 0 V, f = 1 MHz, E = 0)	(typ)	C_0	25	pF
Temperature coefficient of V_O	(typ)	TC_V	-2.6	mV / K
Temperature coefficient of I_{SC} (Std. Light A)	(typ)	TC_I	0.18	% / K
Noise equivalent power (V_R = 10 V, λ = 850 nm)	(typ)	NEP	0.103	pW / $Hz^{½}$
Detection limit (V_R = 10 V, λ = 850 nm)	(typ)	D^*	1.2e12	cm x $Hz^{½}$ / W

Relative Spectral Sensitivity 1) *page 7*
$S_{rel} = f(\lambda)$



Photocurrent / Open-Circuit Voltage 1) *page 7*
I_P (V_R = 5 V) / $V_O = f(E_v)$



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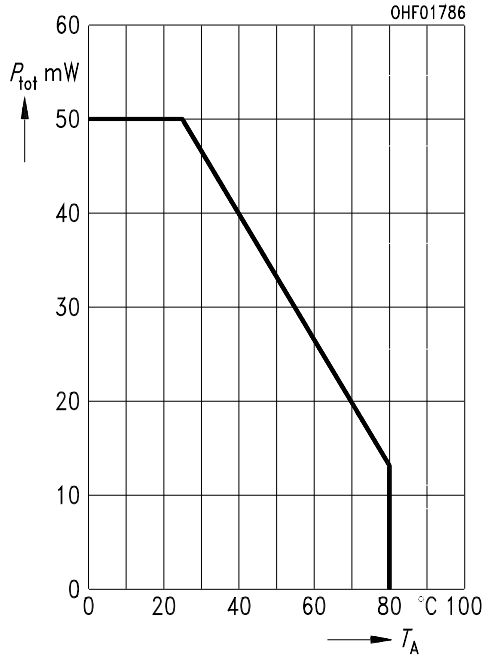
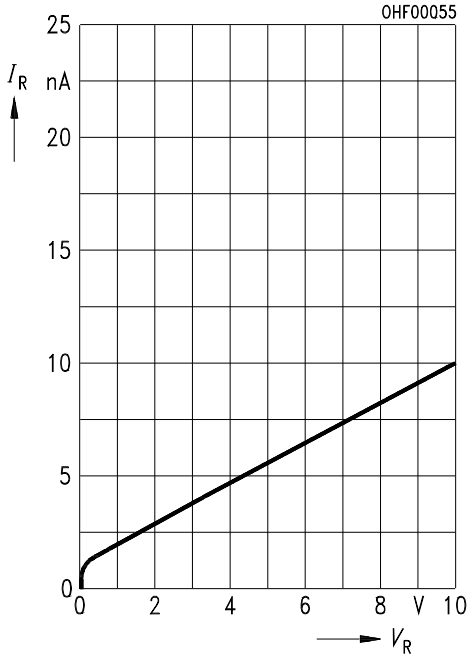
Power Consumption

$P_{tot} = f(T_A)$



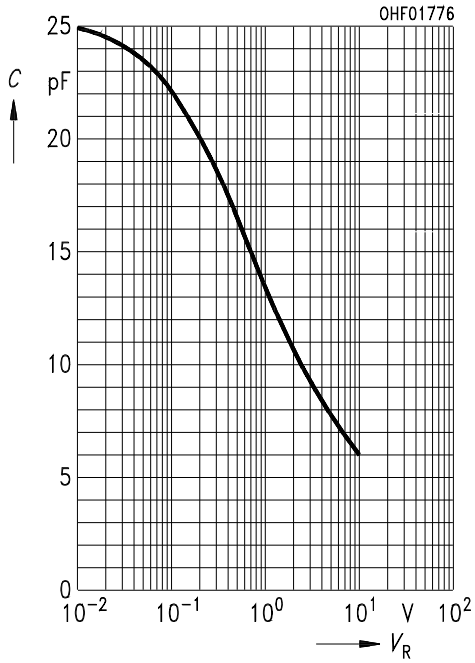
Dark Current [1] *page 7*

$I_R = f(V_R)$, E = 0



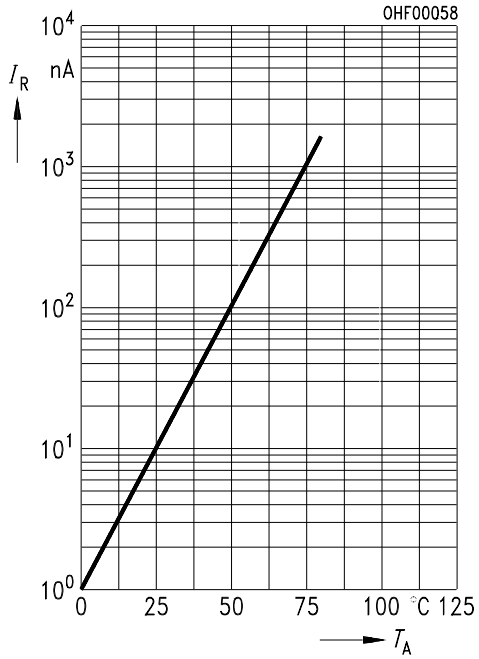
Capacitance [1] *page 7*

$C = f(V_R)$, f = 1 MHz, E = 0



Dark Current [1] *page 7*

$I_R = f(T_A)$, V_R = 10 V, E = 0



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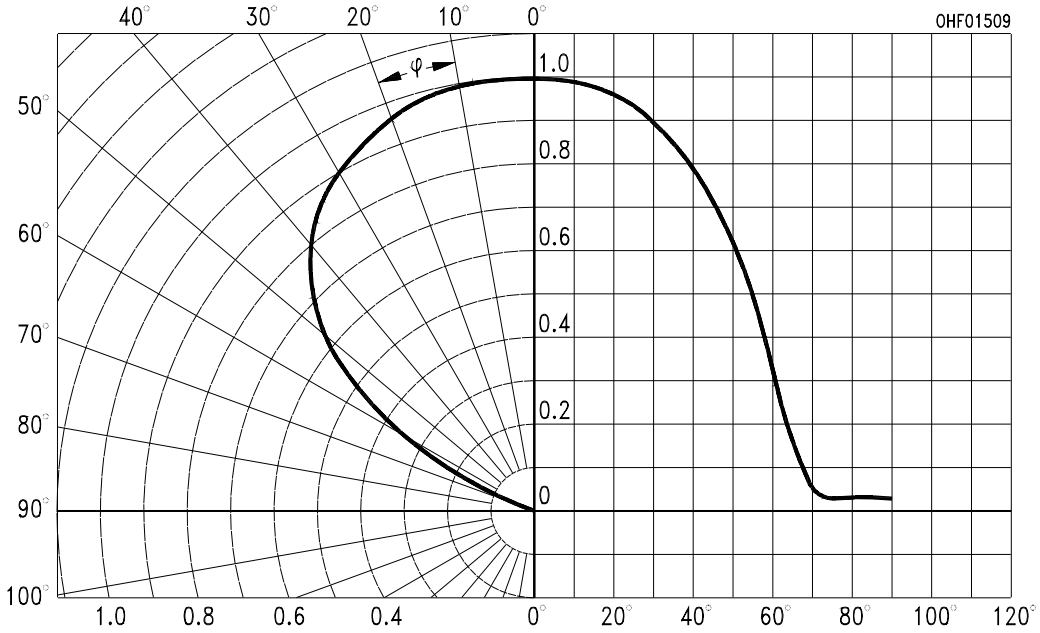
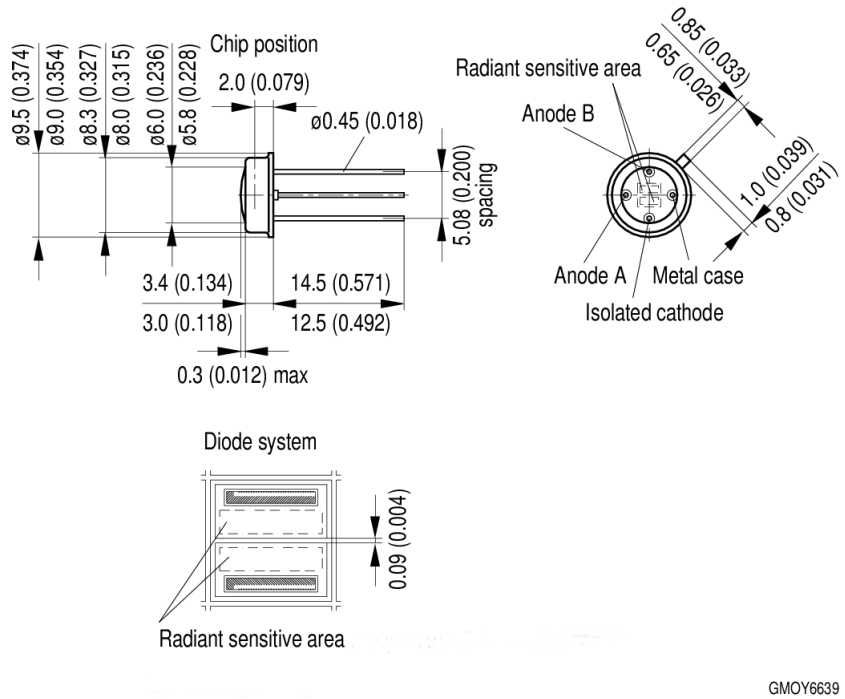
Directional Characteristics [1] *page 7*

$S_{rel} = f(\phi)$



Package Outline



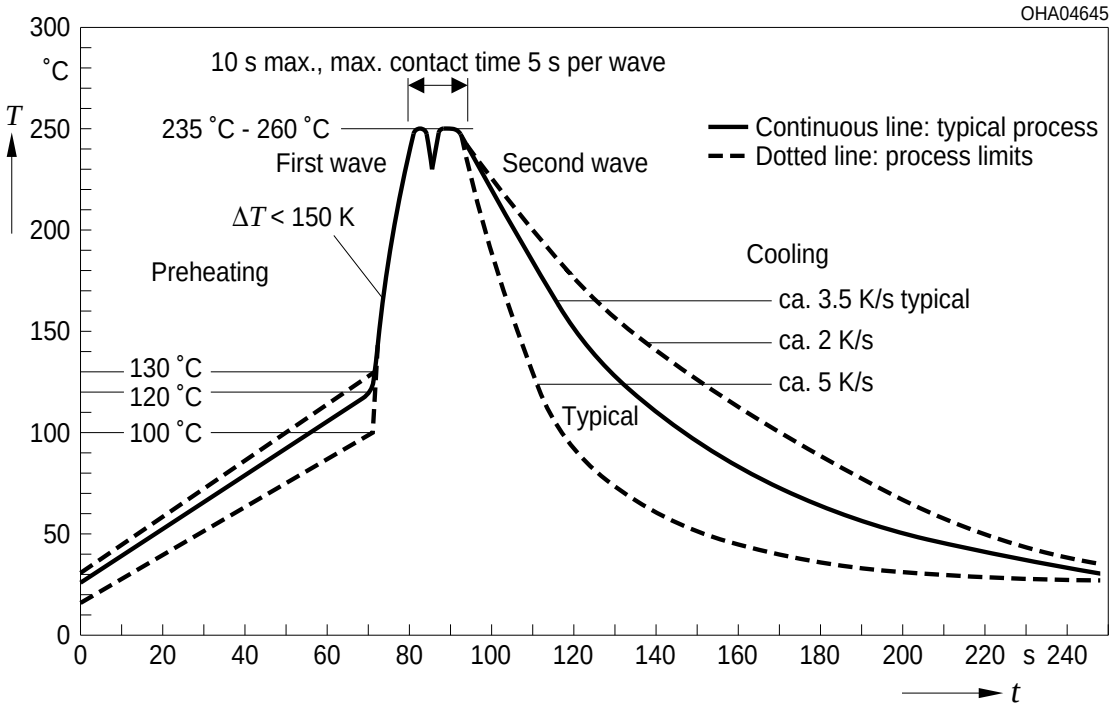
Dimensions in mm (inch).

Package

Metal Can (TO-39), hermetically sealed

Approximate Weight:
0.8 g

TTW Soldering
IEC-61760-1 TTW



Disclaimer

Language english will prevail in case of any discrepancies or deviations between the two language wordings.

Attention please!
The information describes the type of component and shall not be considered as assured characteristics.
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For information on the types in question please contact our Sales Organization.
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Critical components* may only be used in life-support devices** or systems with the express written approval of OSRAM OS.

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**) Life support devices or systems are intended (a) to be implanted in the human body, or (b) to support and/or maintain and sustain human life. If they fail, it is reasonable to assume that the health and the life of the user may be endangered.

Glossary

[1] **Typical Values:** Due to the special conditions of the manufacturing processes of LED, the typical data or calculated correlations of technical parameters can only reflect statistical figures. These do not necessarily correspond to the actual parameters of each single product, which could differ from the typical data and calculated correlations or the typical characteristic line. If requested, e.g. because of technical improvements, these typ. data will be changed without any further notice.

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